

Midium Power Transistors (-80V / -0.7A)

2SAR514P

Structure

PNP Silicon epitaxial planar transistor

Features

- 1) Low saturation voltage, typically $V_{CE \, (sat)} = -0.4 V \, (Max.) \, (I_C \, / \, I_B = -300 mA \, / \, -15 mA)$
- 2) High speed switching

Applications

Driver

Packaging specifications

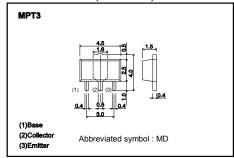
Type	Package	Taping
	Code	T100
	Basic ordering unit (pieces)	1000
2SAR514P		0

◆ Absolute maximum ratings (Ta = 25°C)

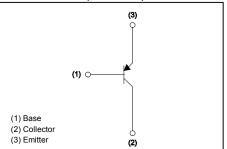
Parameter		Symbol Limits		Unit
Collector-base voltage		V_{CBO}	-80	V
Collector-emitter voltage		V_{CEO}	-80	V
Emitter-base voltage		V_{EBO}	-6	V
Collector current	DC	Ic	-0.7	Α
	Pulsed	I _{CP} *1	-1.4	Α
Power dissipation		P _D *2	0.5	W
		P _D *3	2	W
Junction temperature		Tj	150	°C
Range of storage temperature		T_{stg}	-55 to 150	°C

^{*1} Pw=10ms, Single Pulse

Dimensions (Unit : mm)



Inner circuit (Unit : mm)



^{*2} Each terminal mounted on a recommended land.

^{*3} Mounted on a ceramic board. (40x40x0.7mm³)

2SAR514P Data Sheet

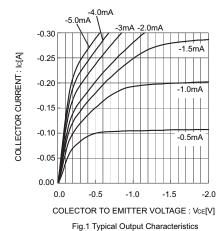
●Electrical characteristic (Ta = 25°C)

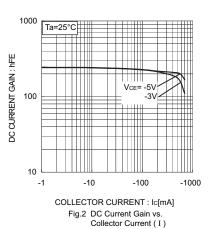
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-emitter breakdown voltage	BV _{CEO}	-80	-	-	V	I _C = -1mA	
Collector-base breakdown voltage	BV _{CBO}	-80	-	-	V	I _C = -100μA	
Emitter-base breakdown voltage	BV_{EBO}	-6	-	-	V	I _E = -100μA	
Collector cut-off current	I _{CBO}	-	-	-1	μA	V _{CB} = -80V	
Emitter cut-off current	I _{EBO}	-	-	-1	μA	V _{EB} = -4V	
Collector-emitter staturation voltage	$V_{\text{CE(sat)}}$	-	-200	-400	mV	I_C = -300mA, I_B = -15mA	
DC current gain	h _{FE}	120	-	390	-	V_{CE} = -3V, I_{C} = -100mA	
Transition frequency	f _T	-	380	ı	MHz	V _{CE} = -10V I _E =200mA, f=100MHz	
Collector output capacitance	C _{ob}	-	10	ı	pF	V _{CB} = -10V, I _E =0A f=1MHz	
Turn-on time	t _{on} * ₁	1	50	-	ns	I = 0.25A I = 25mA	
Storage time	t _{stg} * ₁	-	350	-	ns	I _C = -0.35A, I _{B1} = -35mA I _{B2} =35mA, V _{CC} ~-10V	
Fall time	t _f *1	-	50	-	ns	182 00.1.1.1, VCC 10V	

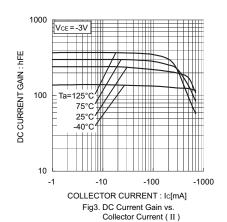
^{*1} See switching time test circuit

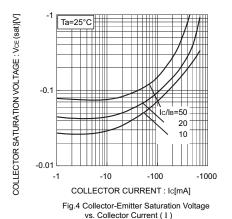
2SAR514P Data Sheet

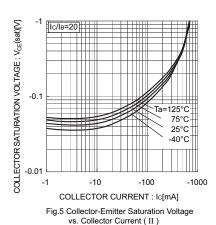
•Electrical characteristic curves

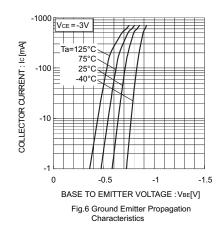


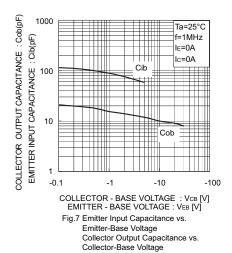


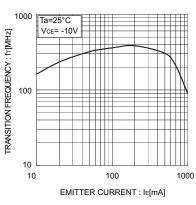












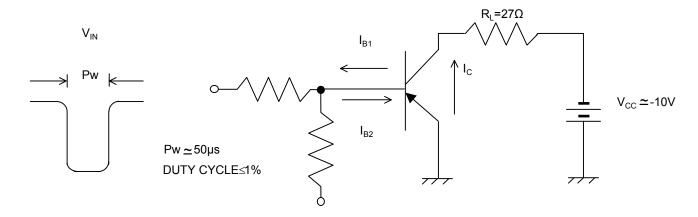
ON COLLECTOR TO EMITTER VOLTAGE: Voe[V]

Fig.8 Gain Bandwidth Product vs. Emitter Current

Fig.9 Safe Operating Area

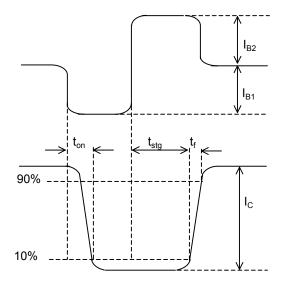
2SAR514P Data Sheet

•Switching time test circuit



BASE CURENT WAVEFORM

COLLECTOR CURRENT WAVEFORM



Notes

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